

NSN 5961-01-645-7367

Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

0.170 inches

Mounting Method:

Terminal

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

10.0 base to collector voltage, dc

Current Rating Per Characteristic:

10.0 milliamperes base current, dc

Power Rating Per Characteristic:

360.0 milliwatts average gate power dissipation

Product Name:

Semiconductor device

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fig:

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